

With Conversion Dynode, Off-axis Structure
for Gas / liquid QMS (Quadruple Mass Spectrometry)

SPECIFICATIONS

GENERAL

Parameter	Description / Value	Unit
Input Aperture Diameter	φ11	mm
Dynode Structure	Conversion + box and linear focused	—
Number of Dynode Stages	19	—
First Dynode Material	Al ₂ O ₃	—
Total Built-in Resistance	17.15	MΩ
Operating Ambient Temperature	-30 to +50	°C
Storage Temperature	-80 to +50	°C
Polarity of Detected Ions	Positive / Negative	—

MAXIMUM RATINGS

Parameter	Value	Unit
Anode to First Dynode Voltage	-3000	V
Anode to Last Dynode Voltage	350	V
Conversion Supply Voltage	±10	kV
Operating Vacuum Level	1 × 10 ⁻²	Pa
Bake-Out Temperature (at 5 × 10 ⁻³ Pa)	No baking	—
Average Anode Current ^(A)	10	μA
Operating Gain	1 × 10 ⁸	—

CHARACTERISTICS

Parameter	Value	Unit
Recommended Supply Voltage	-1900	V
Gain (Typ.)	1 × 10 ⁶	—
DC Linearity (Typ.)	5	μA
Dark Current (Max.)	1	pA
Rise Time (Typ.)	4.5	ns
Anode to All Other Electrode Capacitance	1.8	pF

NOTE: (A) Averaged over any interval of 30 seconds maximum.

Figure 2: Dimensional Outline (Unit: mm)

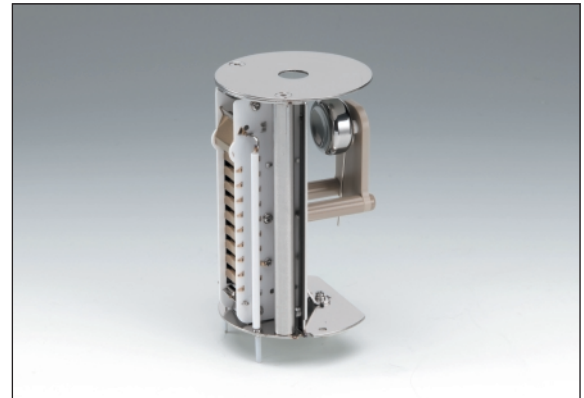
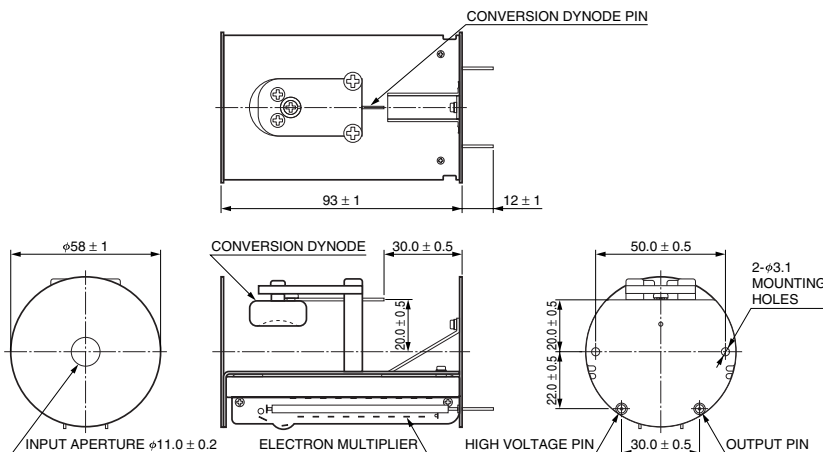
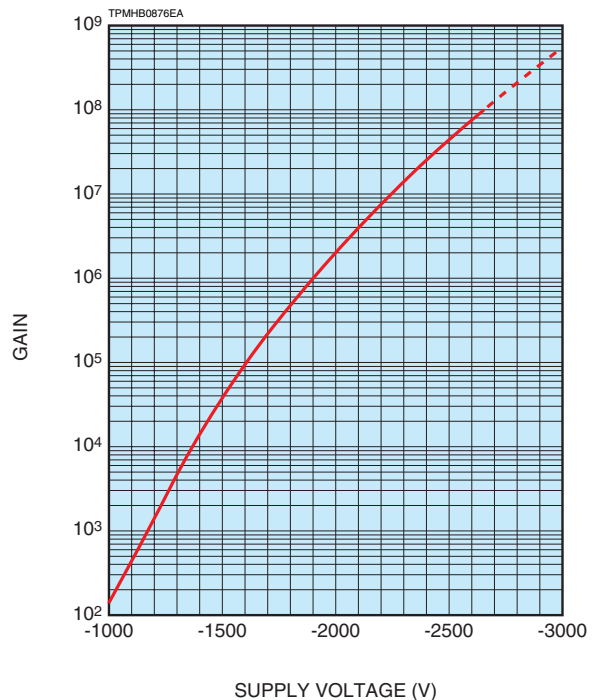
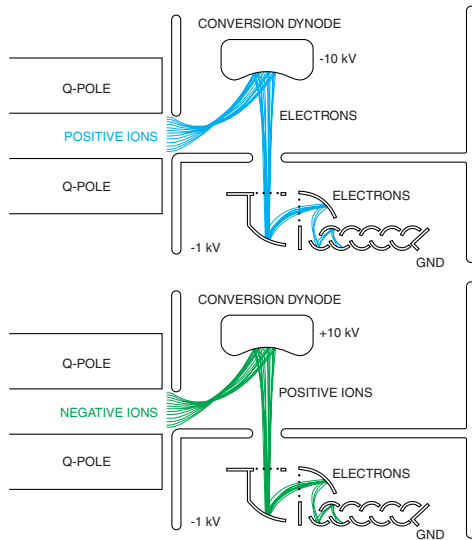


Figure 1: Typical Gain



ELECTRON MULTIPLIER R6985-80

POSITIVE ION / NEGATIVE ION DETECTION MECHANISM



TPMHC0248EA

When positive ions strike the conversion dynode, electrons are emitted from the conversion dynode according to the quantity of input ions. These emitted electrons are then guided into the electron multiplier for secondary multiplication.

When negative ions strike the conversion dynode, positive ions are emitted from the conversion dynode according to the quantity of input ions. These emitted positive ions then enter the electron multiplier while receiving energy from the difference in potential between the conversion dynode and electron multiplier, and strike the first dynode of the electron multiplier where electrons are released according to the quantity of input positive ions. These electrons are then guided to the second and subsequent dynodes for secondary multiplication.

HAMAMATSU PHOTONICS K.K. www.hamamatsu.com

HAMAMATSU PHOTONICS K.K., Electron Tube Division

314-5, Shimokanzo, Iwata City, Shizuoka Pref., 438-0193, Japan, Telephone: (81)539/62-5248, Fax: (81)539/62-2205

U.S.A.: Hamamatsu Corporation: 360 Foothill Road, Bridgewater, N.J. 08807-0910, U.S.A., Telephone: (1)908-231-0960, Fax: (1)908-231-1218 E-mail: usa@hamamatsu.com

Germany: Hamamatsu Photonics Deutschland GmbH: Arzbergerstr. 10, D-82211 Herrsching am Ammersee, Germany, Telephone: (49)8152-375-0, Fax: (49)8152-2658 E-mail: info@hamamatsu.de

France: Hamamatsu Photonics France S.A.R.L.: 19, Rue du Saule Trapu, Parc du Moulin de Massy, 91882 Massy Cedex, France, Telephone: (33)1 69 53 71 00, Fax: (33)1 69 53 71 10 E-mail: infos@hamamatsu.fr

United Kingdom: Hamamatsu Photonics UK Limited: 2 Howard Court, 10 Tewin Road, Welwyn Garden City, Hertfordshire AL7 1BW, United Kingdom, Telephone: (44)1707-294888, Fax: (44)1707-325777 E-mail: info@hamamatsu.co.uk

North Europe: Hamamatsu Photonics Norden AB: Torshamnsgatan 35 SE-164 40 Kista, Sweden, Telephone: (46)8-509-031-00, Fax: (46)8-509-031-01 E-mail: info@hamamatsu.se

Italy: Hamamatsu Photonics Italia S.r.l.: Strada della Moia, 1 int. 6, 20020 Arese (Milano), Italy, Telephone: (39)02-93581733, Fax: (39)02-93581741 E-mail: info@hamamatsu.it

China: Hamamatsu Photonics (China) Co., Ltd.: B1201 Jiaming Center, No.27 Dongsanhuan Beilu, Chaoyang District, Beijing 100020, China, Telephone: (86)10-6586-6006, Fax: (86)10-6586-2866 E-mail: hpc@hamamatsu.com.cn

TPMH1339E02

AUG. 2014 IP